

Silicon Zener Diodes



Glass Axial Leaded

Low Level, Very Low Voltage, Low Leakage

| Model | Zener Voltage Vdc | Dynamic Impedance Ω | | Reverse Current | |
|------------------------|---|---|--|-----------------------------|-----------------------|
| | | | | I _r μ Adc | V _r Vdc |
| | TYP | MAX | MAX | MAX | |
| K120 | 1.2 | 20 | 125 | .05 | 0.4 |
| K150 | 1.5 | 20 | 125 | .05 | 0.5 |
| K180 | 1.8 | 20 | 125 | .05 | 0.6 |
| K210 | 2.1 | 20 | 125 | .05 | 0.9 |
| K240 | 2.4 | 20 | 125 | .05 | 1.2 |
| K270 | 2.7 | 20 | 125 | .05 | 1.7 |
| K300 | 3.0 | 20 | 125 | .05 | 1.9 |
| K330 | 3.3 | 20 | 125 | .05 | 2.2 |
| K360 | 3.6 | 20 | 125 | .05 | 2.5 |
| K390 | 3.9 | 20 | 125 | .05 | 2.7 |
| K430 | 4.3 | 25 | 135 | .05 | 3.1 |
| K470 | 4.7 | 25 | 135 | .05 | 3.5 |
| K510 | 5.1 | 25 | 135 | .05 | 3.8 |
| Test Conditions | V _z @ I _z = 10 mA | Z _z @ I _z = 10 mA | Z _K @ I _z = 1 mA | @25° C | |
| Maximum Rating | Parameters | Value | | Rating | |
| | DC Power Dissipation | @ T _a = 50° C | | 250 mW | |
| | Operating Temperature (T _{OPR}) | -65 to + 175° C | | | |
| | Storage Temperature (T _{STG}) | -65 to + 200° C | | | |
| | Voltage Tolerance: | Standard Device | | +10% | |
| | Other package styles available | | | | |